

DATASHEET

MS9000.D / Single axis analog accelerometer

30S.MS9XXX.I.10.13

Energy Mil/Aerospace Industrial





- ±1g to ±200g range
- Excellent bias stability (less than 0.05% of full scale)
- Single power supply (+2.5V to +5.5V, ratiometric voltage output)
- Low power
- Extra small 20 pin LCC ceramic package with hermetic sealing (8.9mm x 8.9mm)
- Individually calibrated (bias, scale factor and non linearity)
- Brown out protected
- RoHS compliant suitable for lead free soldering process and SMD mounting



The MS9000 product is a single axis MEMS capacitive accelerometer based on a bulk micro-machined silicon element specifically designed for high stability, a low power ASIC for signal conditioning, a micro-controller for storage of compensation values and a temperature sensor. The product is low power, fully calibrated, robust and extremely stable and the electronic configuration provides a solid power on reset and ensures a full protection against brown-out.

It operates from a single power supply voltage (between +2.5V and +5.5V) with low current consumption (< 0.5mA at 5V). The output is a ratiometric analog voltage that varies between +0.5V and +4.5V for the full-scale acceleration range at a voltage supply of +5V. The sensor is fully self-contained and packaged in a 20-pin LCC ceramic housing, thus insuring a full hermeticity.

Accelerometer specifications

All values are specified at +20°C (+68°F) and 5.0 VDC supply voltage, unless otherwise stated

	Units	MS9001	MS9002	MS9005	MS9010	MS9030	MS9050	MS9100	MS9200
Full scale range	g	± 1g	± 2g	± 5g	± 10g	± 30g	± 50g	± 100g	± 200g
Bias calibration	mg	< 5	< 10	< 25	< 50	< 150	< 250	< 500	< 1000
One year bias stability @ 6000g [1]	mg typ. (max.)	0.75 (< 2.5)	1.5 (< 5)	3.75 (< 12.5)	7.5 (< 25)	22 (< 75)	37.5 (< 125)	75 (< 250)	150 (< 500)
One year bias stability @ 1000g [2]	mg typ. (max.)	0.15 (< 0.75)	0.3 (< 1.5)	0.75 (< 3.75)	1.5 (< 7.5)	4.5 (< 22.5)	7.5 (< 37.5)	15 (< 75)	30 (< 150)
Switch on/off repeatability	mg max.	< 0.1	< 0.15	< 0.375	< 0.75	< 1.5	< 3.8	< 7.5	< 15
Bias temp. coefficient [3]	mg/°C typ.	< 0.05	< 0.1	< 0.25	< 0.5	< 1.5	< 2.5	< 5	< 10
	mg/°C max.	± 0.2	± 0.4	±1	± 2	±6	± 10	± 20	± 40
Scale factor sensitivity (K1)	mV/g	2000 ± 8	1000 ± 8	400 ± 4	200 ± 2	66.6 ± 1	40 ± 1	20 ± 1	10 ± 1
One year scale factor stability [1] & [2]	ppm typ. (max.)	300 (< 1000)	300 (< 1000)	300 (< 1000)	300 (< 1000)	300 (< 1000)	300 (< 1000)	300 (< 1000)	300 (< 1000)
Scale factor temp. coefficient [3]	ppm / °C typ.	100	100	100	100	100	100	100	100
	min. / max.	-50 / 250	-50 / 250	-50 / 250	-50 / 250	-50 / 250	-50 / 250	-50 / 250	-50 / 250
Input axis misalignment (Kp, Ko)	mrad max.	< 10	< 10	< 10	< 10	< 10	< 10	< 10	< 10
	% max	1	1	1	1	1	1	1	1
Resolution / Threshold (@ 1Hz)	mg max.	< 0.05	< 0.1	< 0.25	< 0.6	< 1.7	< 2.8	< 5.5	< 11
Non linearity	% of FS max.	< 1	< 0.8	< 0.8	< 0.9	< 0.9	< 0.9	< 1	< 1 [5]
	g max.	< 0.01	< 0.02	< 0.04	< 0.09	< 0.27	< 0.50	< 1	< 2 [5]
Bandwidth [4]	Hz	0 to ≥ 100	0 to ≥ 100	0 to ≥ 100	0 to ≥ 100	0 to ≥ 100	0 to ≥ 100	0 to ≥ 100	0 to ≥ 100
Noise spectral density in band	μV/√Hz typ.	18	18	18	18	18	18	18	18
(0; 9kHz)	max.	24	24	24	24	24	24	24	24
Resonant frequency	kHz		1.4	2.9	3.7	6.3	11	15	26

- [1] One year stability defined according to IEEE 528-2001: turn on / on, storage at -55°C and 85°C, -40°C to 125°C T cycling, -55°C to 85°C unpowered
- harass, vibration, shock (6000g, single shock in one axis).

 One year stability defined according to IEEE 528-2001: turn on / on, storage at -55°C and 85°C, -40°C to 125°C T cycling, -55°C to 85°C unpowered harass, vibration, shock (1000g, single shock in one axis).
- Temperature coefficients are specified for a range of -40°C to 20°C, where temperature behavior is typically linear and coefficient are maximum.
- The bandwidth is defined as the frequency band for which the sensitivity has decreased by less than 3dB.

The non linearity specification for ±200g version is validated to maximum ±100g range.

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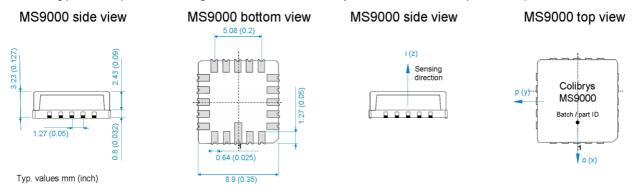
Environmental specifications

	MS9001	MS9002	MS9005	MS9010	MS9030	MS9050	MS9100	MS9200
Operating temperature range	-55°C to +	125°C (-67°F	to 255°F)					
Reliability	Results ba	Results based on MIL-HDBK-217, notice 2, are available on request.						
Shock resistance	Up to 6'00	Up to 6'000 g (0.15ms half-sine, single shock, not repetitive, in one direction o, p or i)						
Recovery time	< 1ms (100	< 1ms (1000g, half-sine period 1ms, shocks in direction i)						
Vibration	20 g rms, 2	20 g rms, 20-2000 Hz (random noise, 30 minutes in each direction o, p, i)						
ESD sensitivity	Class 2 (re	Class 2 (requirements MIL-STD-883-G, 1 Method 3015.7), Human Body Model 2kV						
Ultrasonic cleaning	The produc	The product can't be cleaned with ultrasonic bath. Such a cleaning process will largely affect the sensor integrity						

Packaging

The packaging is a standard LCC ceramic housing with a total of 20 pins. The precise dimensions are given in the next figure and the weight of the final product is typically smaller than 1.5 grams

The sealing process is qualified according to the MIL-STD-883-G and systematical leak tests are performed up to 5·10⁻⁸ atm·cm³/s.



SMD Mounting

The MS9000 is RoHS compliant suitable for lead free soldering process and SMD mounting. It must be tightly fixed to the PCB, using the bottom of the housing as reference plane to ensure a good axis alignment. The stress induced by the soldering of the LCC package is a specific MEMS concern, especially when it comes to high-end capacitive sensors. In order to obtain good stress homogeneity and the best long term stability, all the leads of the accelerometer must be soldered to the pads of the PCB. See the Colibrys Application Note "LCC-48 housing, soldering conditions" available on our web site for more information about the LCC mounting process in general.

Physical specifications

	MS9001	MS9002	MS9005	MS9010	MS9030	MS9050	MS9100	MS9200
Packaging	Non magne	tic, LCC, 20	pin housing					
Lead finishing	Au plating: Ni plating: W (tungster	0.5 to 1.5 1.27 to 8. 1): 10 to 15 µ	89 µm (typ. 3	to 5 µm)				
Hermeticity	The product 5-10 ⁻⁸ atm-c		ualified accord	ding to MIL-ST	D-833-G. Her	metic sealing	s systematica	lly qualified at
Weight	< 1.5 grams	i						
Size	Typ. 8.9 x 8.9 x 3.23 mm (0.35 x 0.35 x 0.127 inch) Max. 9.2 x 9.2 x 3.5 mm (0.354 x 0.354 x 0.138 inch)							
Proximity effect	The sensor is sensitive to external parasitic capacitance. Moving metallic objects with large mass or parasitic effect at proximity of the accelerometer (mm range) must be avoided to insure best product performances.							
Reference plane for axis alignment	LCC must be tightly fixed to the PCB, using the bottom of the housing as reference plane for axis alignmen Using the lid as reference plane or for assembly may affect specifications and product reliability (i.e. ax alignment and/or lid soldering integrity)							



DATASHEET

Principle of operation

The standard calibration voltage for the MS9000.D is (VDD-VSS) = 5V. Therefore, all specifications are valid for this supply voltage unless otherwise stated. Upon market request, the calibration of the product at a different voltage (between 2.5V and 5.5V) is possible. In such a case, the nominal output signal will vary according to the following equation:

 $Vout = (VDD - VSS) / 2 + Ai \cdot (K1 \cdot VDD / 5)$ VAGND = (VDD - VSS) / 2

According to this equation (1), the bias and scale factor are ratiometric to the power supply voltage.

A reference voltage VAGND is also provided at half of the power supply and corresponds to the output voltage at zero g. All sensors are calibrated to match the ideal response curve in term of offset, gain and non-linearity.

At every power-up, the microcontroller, used as memory, transfers the calibration parameters to the ASIC and then goes in a sleep mode. During this initialization phase, which takes less than 50ms, the current consumption goes up to max. 1,5mA @ 5V and at room temperature. Then, the normal operating current is set and remains less than 400µA under similar conditions.

The following model describes each sensor:

Vout = $k_{1} \cdot (k_0 + A_i + k_2 A_i^2 + k_3 A_i^3 + k_p A_p + k_o A_o + k_{ip} A_i A_p + k_{io} A_i A_o + E)$

where

Ai, Ap, Ao are the accelerations for each axes of the sensor with:

I: input axis (z axis)

p: pendulous axis (y axis)

o: output axis, also named pivot or hinge axis (x axis)

K1 is accelerometer scale factor [V/g]

K0 is bias [g]

K2 is second order non linearity [g/g2] K3 is third order non-linearity [g/g3]

is pendulous cross axis non linearity [rad] Kp Ko is output cross axis non linearity [rad] Kip. Kio are cross-coupling coefficients [rad/g]

is the residual noise [g] Ε

Electrical specifications

	MS9001	MS9002	MS9005	MS9010	MS9030	MS9050	MS9100	MS9200
Input voltage (VDD – VSS)	2.5 to 5.5 V	DC. The star	ndard voltage	for calibration	is 5.0 VDC.			
Output voltage range	From 0.5 to	From 0.5 to 4.5 VDC @ 5.0 VDC input voltage (VDD/2 at 0g)						
Operating current consumption	< 400 μΑ @	< 400 μA @ 5.0 VDC						
Initialization & reset current consumption	Typ. 1500 μA @ 5.0 VDC during the initialization phase (less than 35 ms at room temperature)							
Reset	The sensor is Brown out protected. A reset occurs when the power supply jumps more than -0.46 V with a slope >380V/s or if the power supply drops below 2.2V. The recovery time is typ. 25 ms (max 35 ms)							
Output impedance / load	Min. 50 kΩ at Vout (pin 8) and VAGND (pin 5)							
	Max. 50 pF	at Vout (pin	8) and Max. 1	00 μF at VAGI	ND (pin 5)			

Temperature sensor specifications

Output Voltage at 20°C	Typ: 1.632 V
Sensitivity	Typ: -11.77 mV/°C
Long term stability	Max -0.03°C to +0.09°C (1000h @ 150°C)
Accuracy	± 5°C (From -40°C to 125°C)

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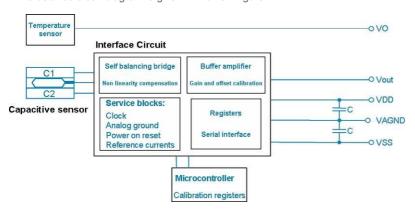
DATASHEET 305 M59XX I 10 13

Temperature compensation

The MS9000 delivers an output signal without any internal temperature compensation. The intrinsic temperature coefficient is quite small but can be further improved through a calibration, using the temperature provided by the internal temperature sensor. Third order compensation is generally required for a coherent modeling of a MS9000.D.

Sensor connections and power supply requirements

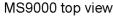
The detailed block diagram is given in the next figure

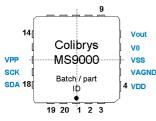


Components in the LCC20 packaging:

- 1-axis silicon MEMS sensor
- ASIC
- Microcontroller
- Temperature sensor
- Pull down resistor

It is strongly recommended to use decoupling capacitors [C] of $1\mu F$ each between VDD and VAGND and between VAGND and VSS, placed as close as possible from the accelerometer. COG or X7R @ 5% capacitor types are recommended. On top, the VAGND track should be as short as possible. Any other setup will potentially affect the bias calibration and stability.





Pin	MS9000 Description	Notes
4	VDD	Power supply
5	VAGND	Accelerometer output reference voltage (VDD / 2)
6	VSS	Ground
7	VO	Temperature sensor output
8	Vout	Accelerometer output signal
16	VPP (Colibrys internal calibration pin)	Must be connected to VSS
17	SCK (Colibrys internal calibration pin)	Must be connected to VSS
18	SDA (Colibrys internal calibration pin)	Must be connected to VSS

Quality







- Colibrys is in compliant with the European Community Regulation on chemicals and their safe use (EC 1907/2006) REACH.
- MS9000 products comply with the EU-RoHS directive 2002/95/EC (Restrictions on hazardous substances) regulations.
- MS9000 products are compliant with the Swiss LSPro: 930.11 dedicated to the security of products





- MS9000 accelerometers are available for sales to professional only
- Les accéléromètres MS9000 ne sont disponibles à la vente que pour des clients professionnels
- Die Produkte der Serie MS9000 sind nur im Vertrieb für kommerzielle Kunden verfügbar
- Gli accelerometri MS9000 sono disponibili alla vendita soltanto per clienti professionisti
- Recycling: please use appropriate recycling process adapted to electrical and electronic components



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DATASHEET 305 M59XXX I 10 13

Glossary of parameters of the Data Sheet

g[m/s²]

Unit of acceleration, equal to standard value of the earth gravity (Accelerometer specifications and data supplied by Colibrys use 9.80665 m/s²)

Bias [mg]

The accelerometer output at zero g

Bias stability [mg]

Maximum drift of the bias after extreme variation of external conditions (aging, temperature cycles, shock, vibration)

Bias temperature coefficient [µq/°C]

Maximum variation of the bias calibration under variable external temperature conditions (slope of the best fit straight line through the curve of bias vs. temperature). Bias Temperature Coefficient is specified between –40°C and +50°C, where temperature behaviour is linear

Scale factor sensitivity [mV/g]

The ratio of the change in output (in volts) to a unit change of the input (in units of acceleration); thus given in mV/g

Scale factor temperature coefficient [ppm/°C]

Maximum deviation of the scale factor under variable external temperature conditions

Temperature sensitivity

Sensitivity of a given performance characteristic (typically scale factor, bias, or axis misalignment) to operating temperature, specified as worst case value over the full operating temperature range. Expressed as the change of the characteristic per degree of temperature change; a signed quantity, typically in ppm/°C for scale factor and g/°C for bias. This figure is useful for predicting maximum scale factor error with temperature, as a variable when modelling is not accomplished

Axis alignment [mrad]

The extent to which the accelerometer's true sensitive axis deviates from being perfectly orthogonal to the accelerometer's reference mounting surface when mounted to a flat surface

Resolution, Threshold [mg]

Value of the smallest acceleration that can be significantly measured

Non-linearity [% of FS]

The maximum deviation of accelerometer output from the best linear fit over the full operating range. The deviation is expressed as a percentage of the full-scale output $(+A_{FS})$.

Bandwidth [Hz]

Frequency range from DC to F-3dB where the variation of the frequency response is less than -3dB or -5% for vibration sensors

Resonant frequency nominal [kHz]

Typical value of the resonant frequency of the mounted system

Noise [μ V/ \sqrt{Hz} or μ g/ \sqrt{Hz}]

Undesired perturbations in the accelerometer output signal, which are generally uncorrelated with desired or anticipated input accelerations

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